



## 2.1 W/CH STEREO FILTER-FREE CLASS-D AUDIO POWER AMPLIFIER

### FEATURES

- 2.1 W/Ch Into 4 Ω at 5 V
  - 1.4 W/Ch Into 8 Ω at 5 V
  - 720 mW/Ch Into 8 Ω at 3.6 V
- Only Two External Components Required
- Power Supply Range: 2.5 V to 5.5 V
- Independent Shutdown Control for Each Channel
- Selectable Gain of 6, 12, 18, and 24 dB
- Internal Pulldown Resistor On Shutdown Pins
- High PSRR: 77 dB at 217 Hz
- Fast Startup Time (3.5 ms)
- Low Supply Current
- Low Shutdown Current
- Short-Circuit and Thermal Protection
- Space Saving Packages
  - 2 mm X 2 mm NanoFree™ WCSP (YZH) (Future Product)
  - 4 mm X 4 mm Pb-Free Thin QFN (RTJ) with PowerPAD™

### APPLICATIONS

- Wireless or Cellular Handsets and PDAs
- Portable DVD Player
- Notebook PC
- Portable Radio
- Portable Gaming
- Educational Toys
- USB Speakers

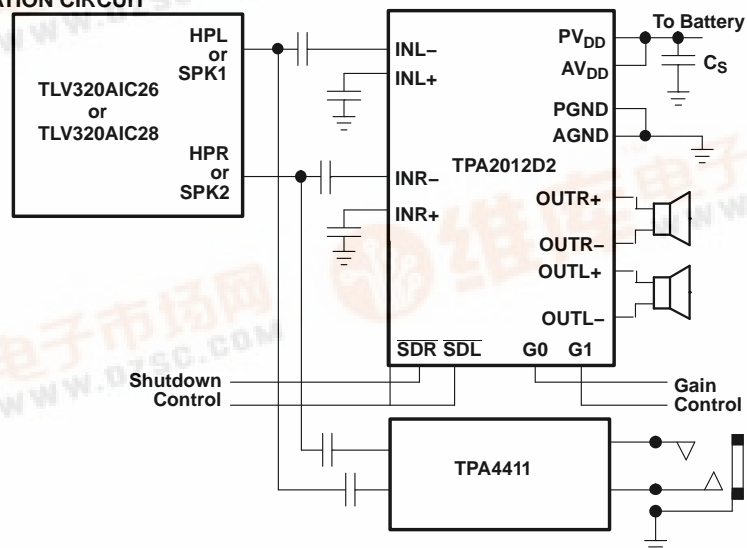
### DESCRIPTION

The TPA2012D2 is a stereo, filter-free Class-D audio amplifier available in a WCSP or QFN package. The TPA2012D2 only requires two external components for operation.

The TPA2012D2 features independent shutdown controls for each channel. The gain can be selected to 6, 12, 18, or 24 dB utilizing the G0 and G1 gain select pins. High PSRR and differential architecture provide increased immunity to noise and RF rectification. In addition to these features, a fast startup time and small package size make the TPA2012D2 an ideal choice for both cellular handsets and PDAs.

The TPA2012D2 is capable of driving 1.4 W/Ch at 5 V or 720 mW/Ch at 3.6 V into 8 Ω. The TPA2012D2 is also capable of driving 4 Ω. The TPA2012D2 provides thermal and short circuit protection.

APPLICATION CIRCUIT





These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

**AVAILABLE OPTIONS**

T <sub>A</sub>	PACKAGE	PART NUMBER	SYMBOL
-40°C to 85°C	2 mm x 2 mm WCSP (YZH)	TPA2012D2YZH	AKR
	4 mm x 4 mm, 20 pin QFN (RTJ)	TPA2012D2RTJ	AKS

**ABSOLUTE MAXIMUM RATINGS**

over operating free-air temperature (unless otherwise noted)<sup>(1)</sup>

		UNITS
V <sub>SS</sub>	Supply voltage, AVDD, PVDD	In active mode -0.3 V to 6.0 V
		In shutdown mode -0.3 V to 7.0 V
V <sub>I</sub>	Input voltage	-0.3 V to V <sub>DD</sub> + 0.3 V
Continuous total power dissipation		See Dissipation Rating Table
T <sub>A</sub>	Operating free-air temperature range	- 40°C to 85°C
T <sub>J</sub>	Operating junction temperature range	- 40°C to 150°C
T <sub>stg</sub>	Storage temperature range	-65°C to 85°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

**DISSIPATION RATING TABLE**

PACKAGE	T <sub>A</sub> = 25°C POWER RATING <sup>(1)</sup>	Derating Factor	T <sub>A</sub> = 75°C POWER RATING	T <sub>A</sub> = 85°C POWER RATING
RTJ	5.2 W	41.6 mW/°C	3.12 W	2.7 W
YZH <sup>(2)</sup>	TBD	TBD	TBD	TBD

(1) This data was taken using 2 oz trace and copper pad that is soldered directly to a JEDEC standard 4-layer 3 in × 3 in PCB.

(2) Product preview

**RECOMMENDED OPERATING CONDITIONS**

			MIN	MAX	UNIT
V <sub>SS</sub>	Supply voltage	AVDD, PVDD	2.5	5.5	V
V <sub>IH</sub>	High-level input voltage	$\overline{SDL}$ , $\overline{SDR}$ , G0, G1	1.3		V
V <sub>IL</sub>	Low-level input voltage	$\overline{SDL}$ , $\overline{SDR}$ , G0, G1		0.35	V
T <sub>A</sub>	Operating free-air temperature		- 40	85	°C

## ELECTRICAL CHARACTERISTICS

over operating free-air temperature range (unless otherwise noted)

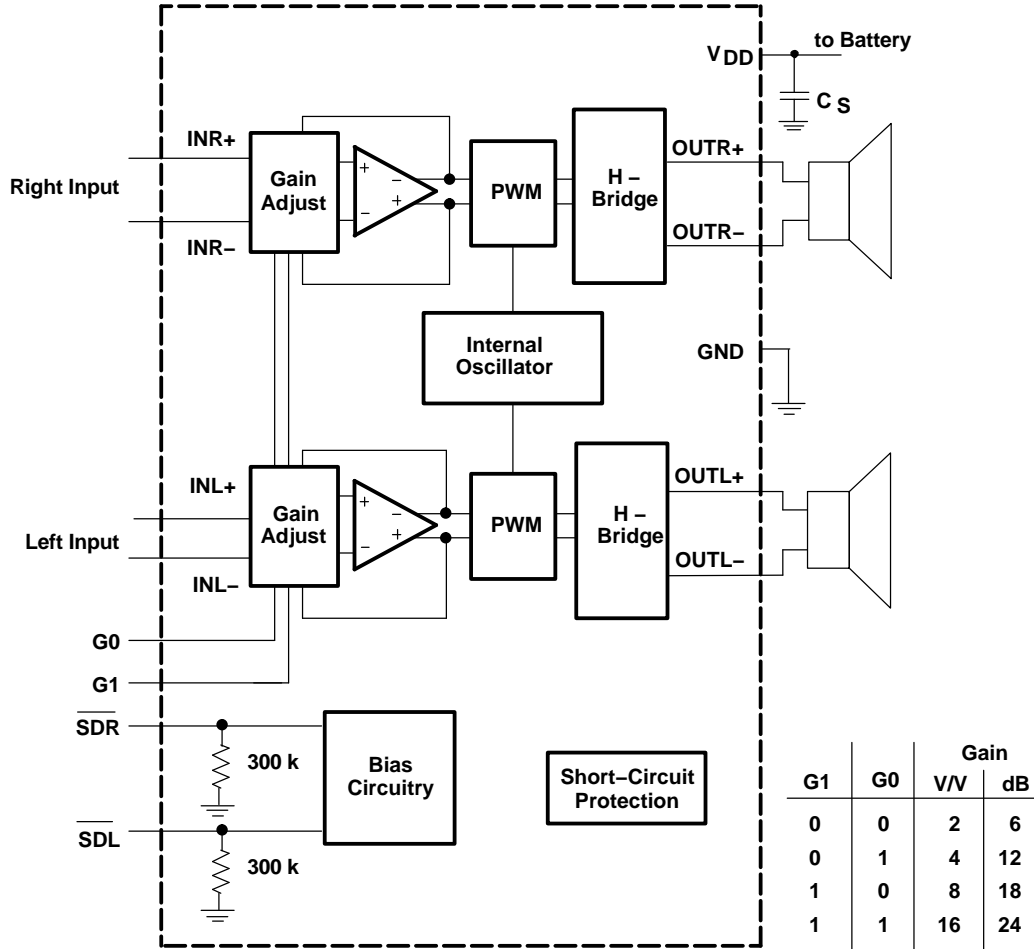
PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$ V_{ool} $	Output offset voltage (measured differentially)	Inputs ac grounded, $A_V = 6$ dB, $V_{DD} = 2.5$ to $5.5$ V		5	25	mV
PSRR	Power supply rejection ratio	$V_{DD} = 2.5$ to $5.5$ V		-75	-55	dB
$V_{icm}$	Common-mode input voltage		0.5		$V_{DD}-0.8$	V
CMRR	Common-mode rejection ratio	Inputs shorted together, $V_{DD} = 2.5$ to $5.5$ V		-69	-50	dB
$ I_{IH} $	High-level input current	$V_{DD} = 5.5$ V, $V_I = V_{DD}$			50	$\mu$ A
$ I_{IL} $	Low-level input current	$V_{DD} = 5.5$ V, $V_I = 0$ V			5	$\mu$ A
$I_{DD}$	Supply current	$V_{DD} = 5.5$ V, No load		6	9	mA
		$V_{DD} = 3.6$ V, No load		5	7.5	
		$V_{DD} = 2.5$ V, No load		4	6	
		Shutdown mode				1.5
$r_{DS(on)}$	Static drain-source on-state resistance	$V_{DD} = 5.5$ V		500		m $\Omega$
		$V_{DD} = 3.6$ V		570		
		$V_{DD} = 2.5$ V		700		
	Output impedance in shutdown mode	$V_{SDR}, V_{SDL} = 0.35$ V		2		k $\Omega$
$f_{(sw)}$	Switching frequency	$V_{DD} = 2.5$ V to $5.5$ V	250	300	350	kHz
	Closed-loop voltage gain	$G_0, G_1 = 0.35$ V	5.5	6	6.5	dB
		$G_0 = V_{DD}, G_1 = 0.35$ V	11.5	12	12.5	
		$G_0 = 0.35$ V, $G_1 = V_{DD}$	17.5	18	18.5	
		$G_0, G_1 = V_{DD}$	23.5	24	24.5	

## OPERATING CHARACTERISTICS

 $T_A = 25^\circ\text{C}$ ,  $R_L = 8 \Omega$ , (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
$P_O$	Output power (per channel)	$R_L = 8 \Omega$	$V_{DD} = 5.0$ V, $f = 1$ kHz, THD = 10%		1.4		W
			$V_{DD} = 3.6$ V, $f = 1$ kHz, THD = 10%		0.72		
		$R_L = 4 \Omega$	$V_{DD} = 5.0$ V, $f = 1$ kHz, THD = 10%		2.1		
THD+N	Total harmonic distortion plus noise	$P_O = 1$ W, $V_{DD} = 5$ V, $A_V = 6$ dB	$f = 1$ kHz		0.14%		
		$P_O = 0.5$ W, $V_{DD} = 5$ V, $A_V = 6$ dB	$f = 1$ kHz		0.11%		
	Channel crosstalk	$f = 1$ kHz			-85		dB
$k_{SVR}$	Supply ripple rejection ratio	$V_{DD} = 5$ V, $A_V = 6$ dB	$f = 217$ Hz		-77		dB
		$V_{DD} = 3.6$ V, $A_V = 6$ dB	$f = 217$ Hz		-73		
CMRR	Common mode rejection ratio	$V_{DD} = 3.6$ V, $V_{IC} = 1 V_{pp}$	$f = 217$ Hz		-69		dB
	Input impedance	$A_V = 6$ dB			28.1		k $\Omega$
		$A_V = 12$ dB			17.3		
		$A_V = 18$ dB			9.8		
		$A_V = 24$ dB			5.2		
	Start-up time from shutdown	$V_{DD} = 3.6$ V			3.5		ms
$V_n$	Output voltage noise	$V_{DD} = 3.6$ V, $f = 20$ to $20$ kHz, Inputs are ac grounded, $A_V = 6$ dB	No weighting		35		$\mu$ V
			A weighting		27		

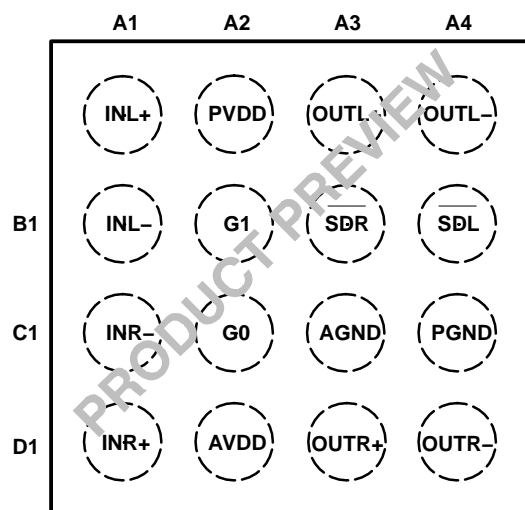
BLOCK DIAGRAM



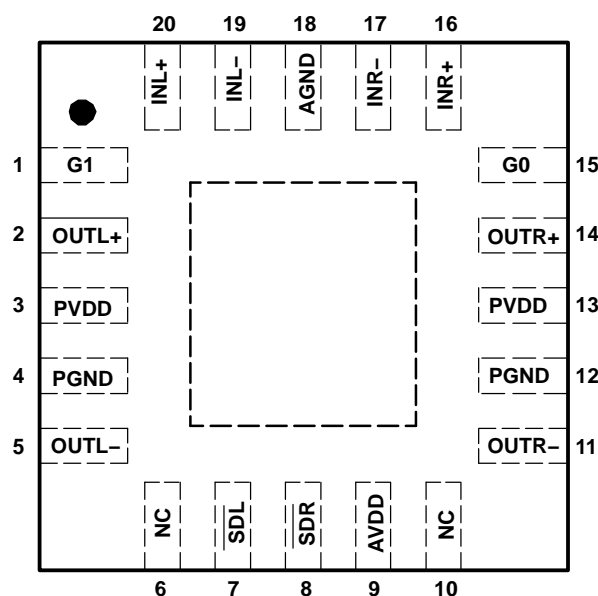
### Terminal Functions

TERMINAL			I/O	DESCRIPTION
NAME	QFN	WCSP		
INR+	16	D1	I	Right channel positive input
INR-	17	C1	I	Right channel negative input
INL+	20	A1	I	Left channel positive input
INL-	19	B1	I	Left channel negative input
$\overline{\text{SDR}}$	8	B3	I	Right channel shutdown terminal (active low)
$\overline{\text{SDL}}$	7	B4	I	Left channel shutdown terminal (active low)
G0	15	C2	I	Gain select (LSB)
G1	1	B2	I	Gain select (MSB)
PVDD	3, 13	A2	I	Power supply (Must be same voltage as AVDD)
AVDD	9	D2	I	Analog supply (Must be same voltage as PVDD)
PGND	4, 12	C4	I	Power ground
AGND	18	C3	I	Analog ground
OUTR+	14	D3	O	Right channel positive differential output
OUTR-	11	D4	O	Right channel negative differential output
OUTL+	2	A3	O	Left channel positive differential output
OUTL-	5	A4	O	Left channel negative differential output
NC	6, 10	N/A		No internal connection
Thermal Pad				Connect the thermal pad of QFN package to GND.

WCSP PIN OUT  
TOP VIEW



RTJ PIN OUT  
TOP VIEW



TYPICAL CHARACTERISTICS

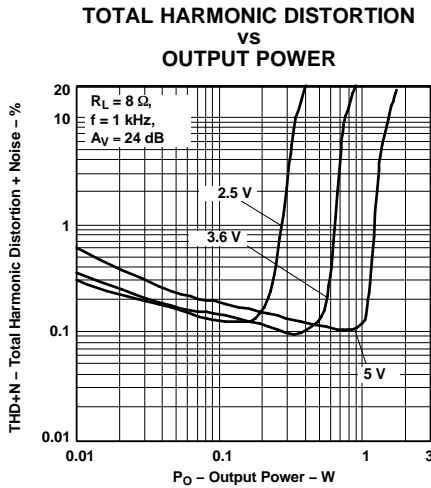


Figure 1.

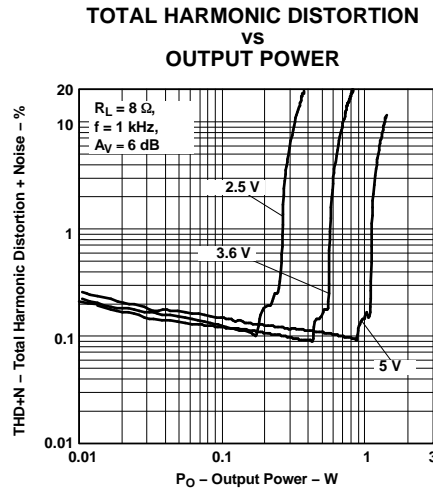


Figure 2.

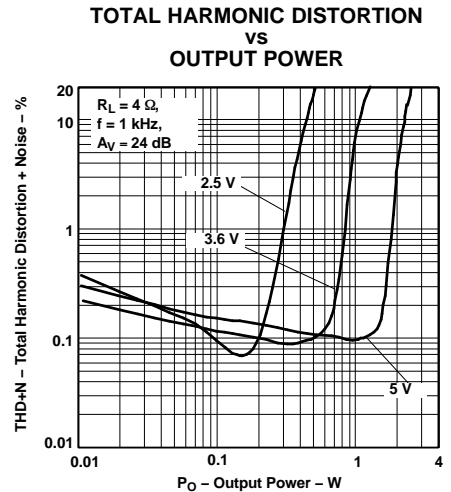


Figure 3.

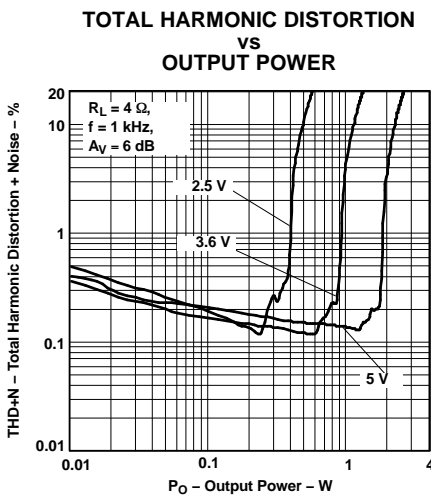


Figure 4.

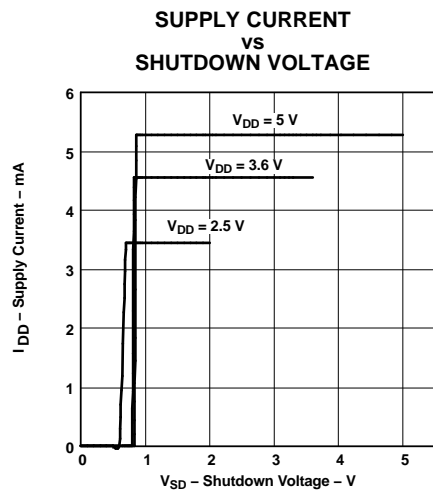


Figure 5.

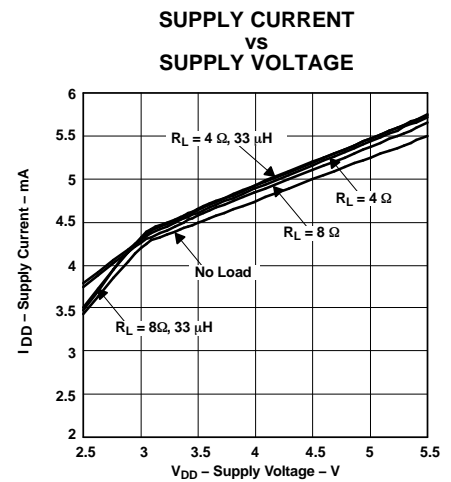


Figure 6.

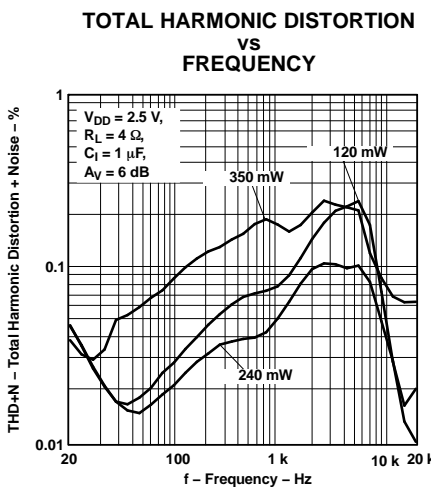


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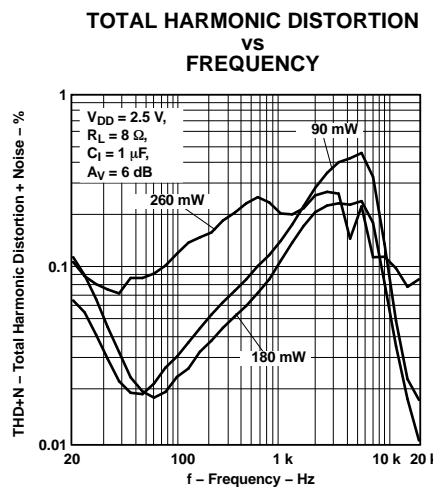


Figure 8.

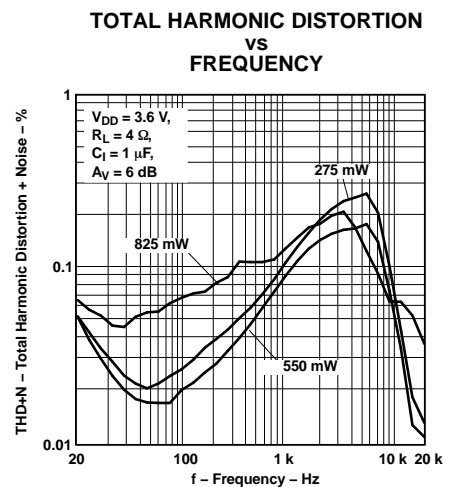


Figure 9.

**TYPICAL CHARACTERISTICS (continued)**

**TOTAL HARMONIC DISTORTION VS FREQUENCY**

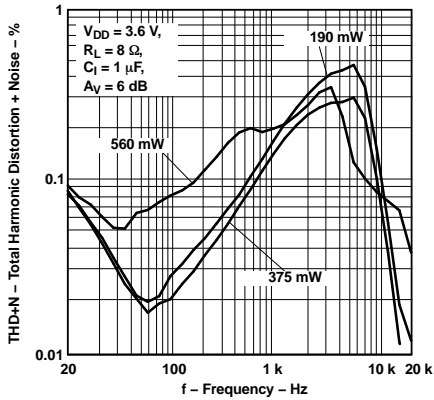


Figure 10.

**TOTAL HARMONIC DISTORTION VS FREQUENCY**

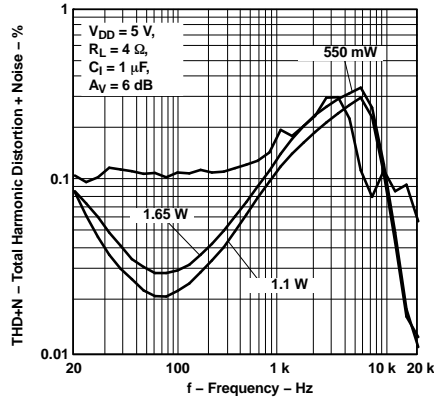


Figure 11.

**TOTAL HARMONIC DISTORTION VS FREQUENCY**

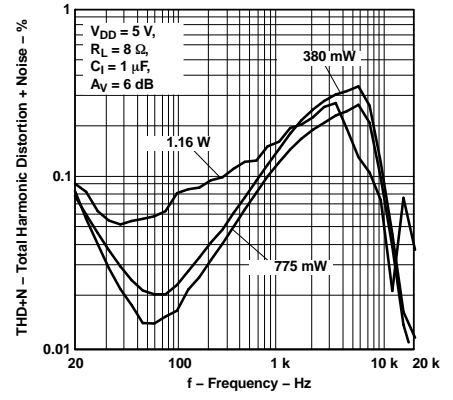


Figure 12.

**CROSSTALK VS FREQUENCY**

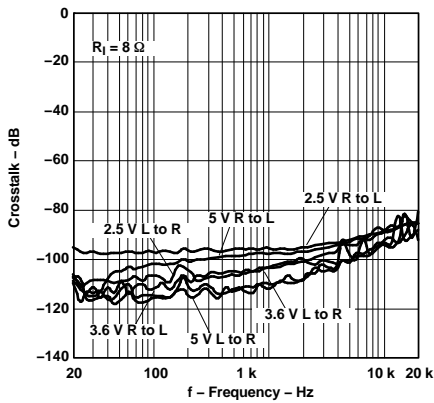


Figure 13.

**CROSSTALK VS FREQUENCY**

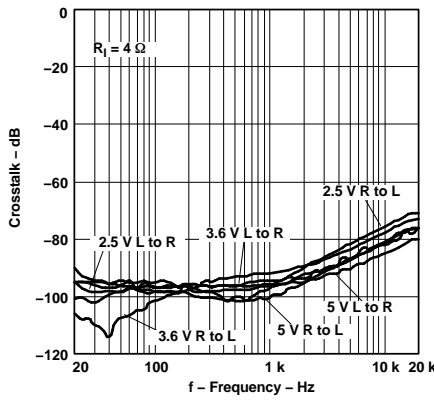


Figure 14.

**POWER SUPPLY REJECTION RATIO VS FREQUENCY**

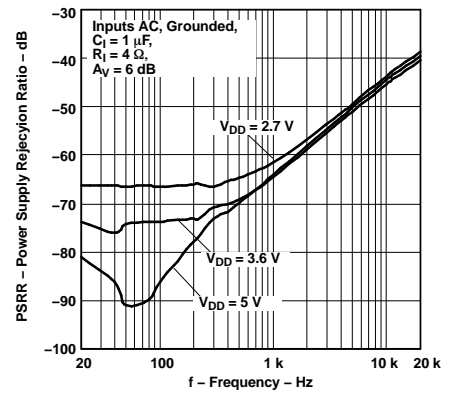


Figure 15.

TYPICAL CHARACTERISTICS (continued)

**POWER SUPPLY REJECTION RATIO VS FREQUENCY**

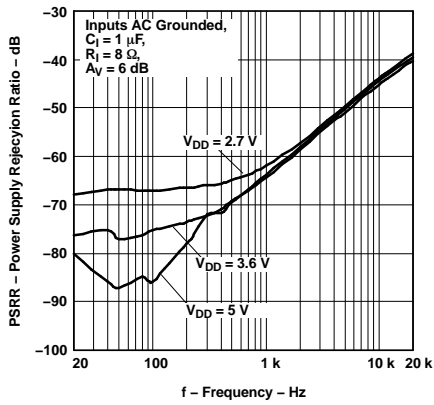


Figure 16.

**COMMON-MODE REJECTION RATIO VS COMMON-MODE INPUT VOLTAGE**

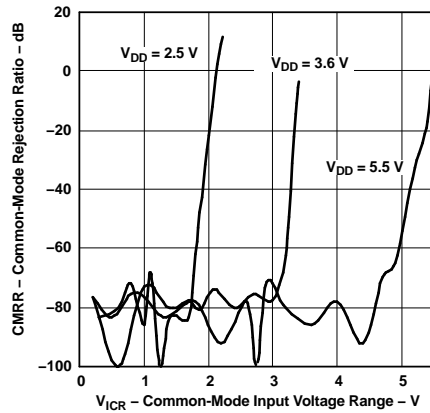


Figure 17.

**COMMON-MODE REJECTION RATIO VS FREQUENCY**

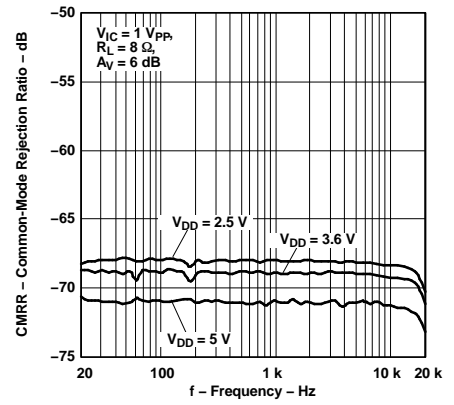


Figure 18.

**GSM POWER SUPPLY REJECTION VS TIME**

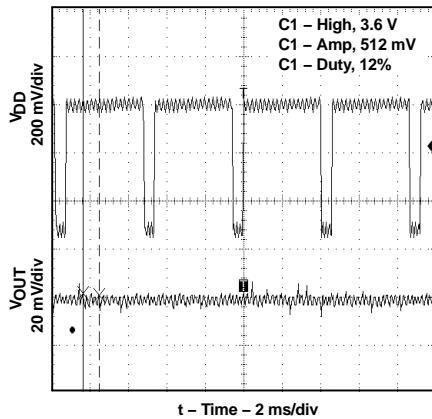


Figure 19.

**POWER SUPPLY REJECTION VS FREQUENCY**

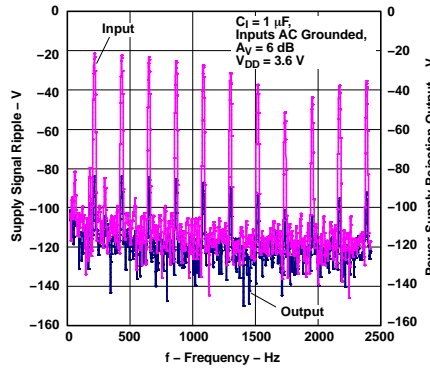


Figure 20.

**POWER DISSIPATION VS OUTPUT POWER**

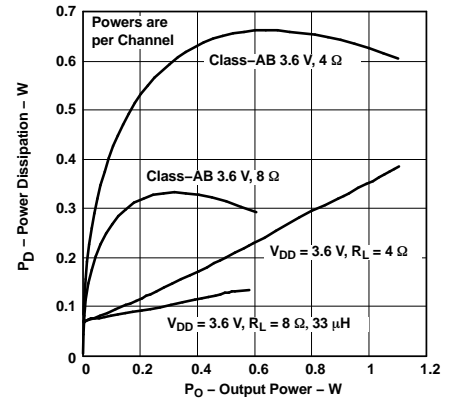


Figure 21.



**TYPICAL CHARACTERISTICS (continued)**

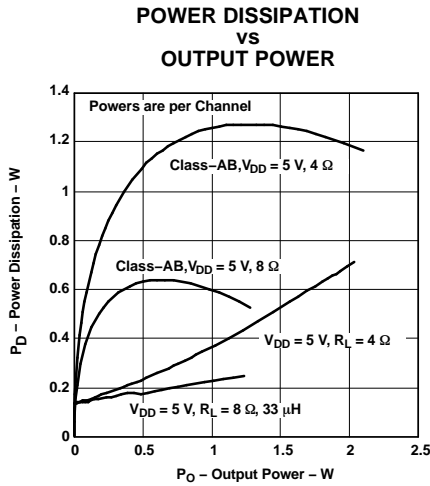


Figure 22.

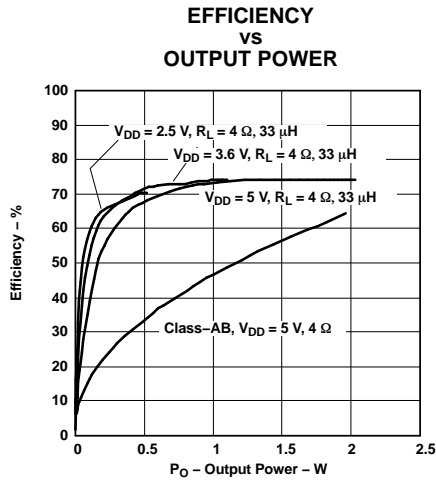


Figure 23.

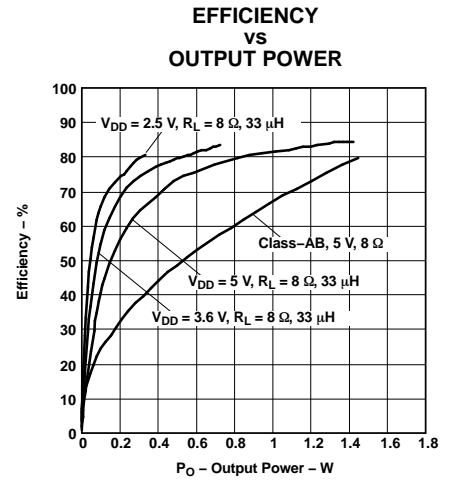


Figure 24.

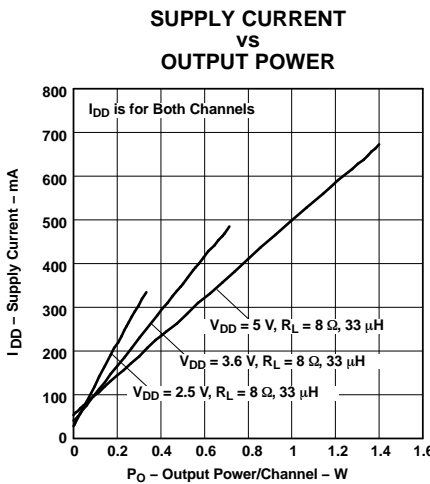


Figure 25.

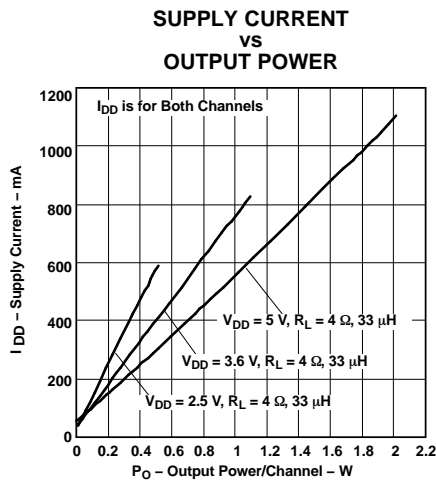


Figure 26.

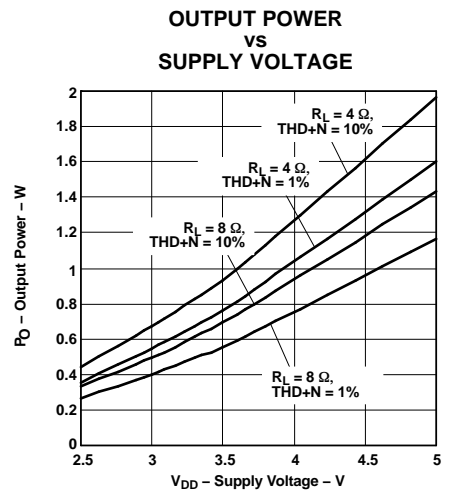


Figure 27.

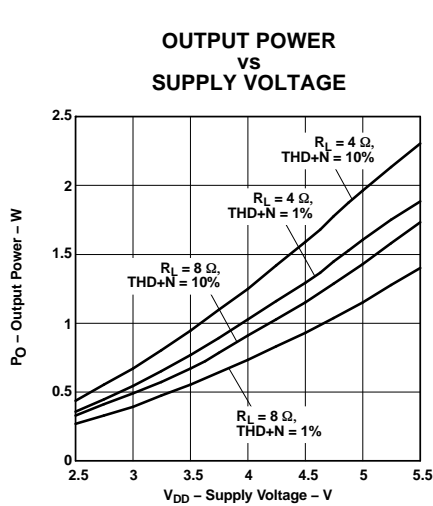


Figure 28.

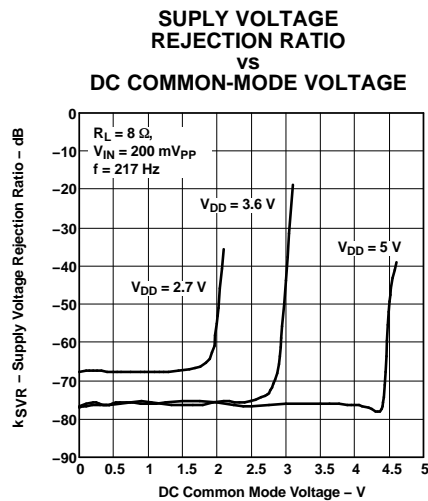
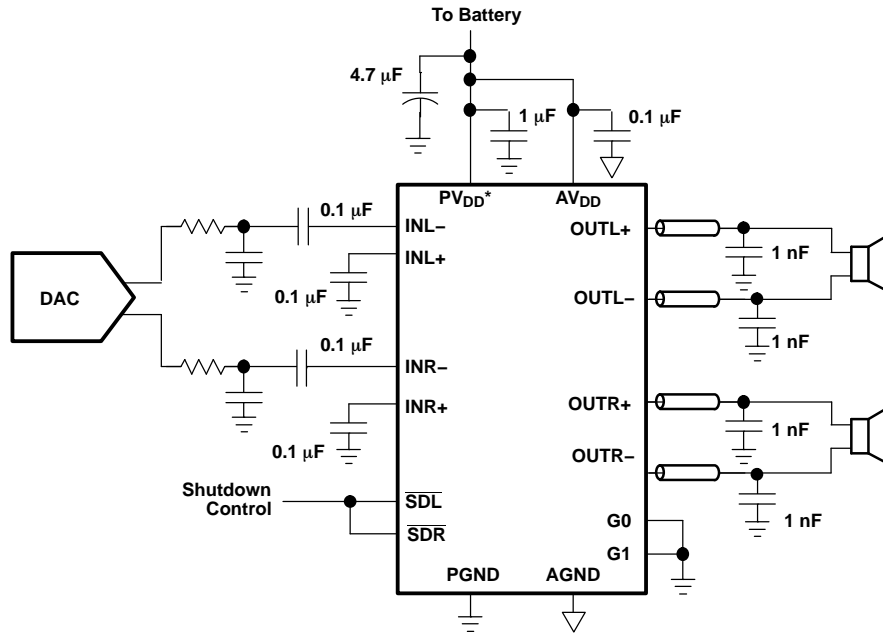


Figure 29.

APPLICATION INFORMATION



\* For QFN, an additional capacitor is recommended for the second PV<sub>DD</sub> pin.

Figure 30. Typical Application Circuit

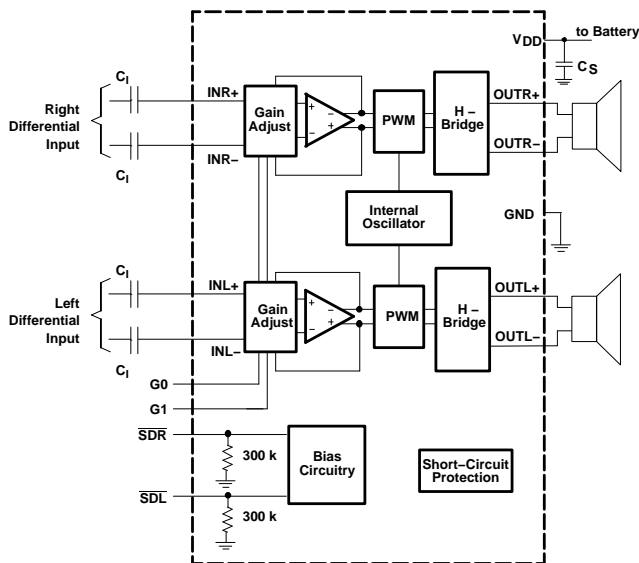


Figure 31. TPA2012D2 Application Schematic With Differential Input and Input Capacitors

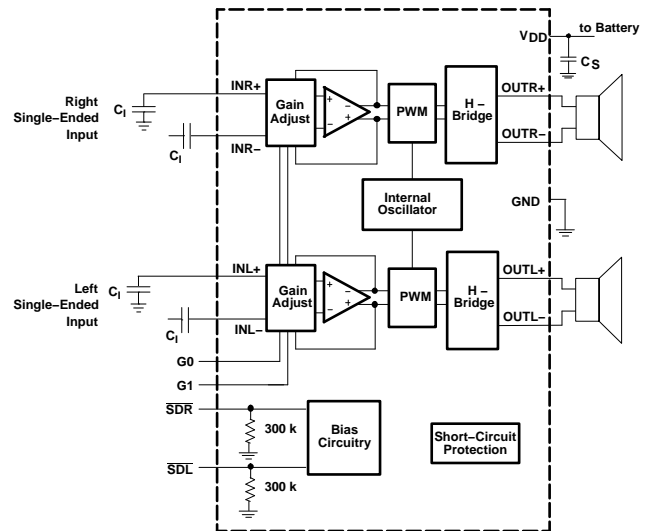


Figure 32. TPA2012D2 Application Schematic With Single-Ended Input

## Decoupling Capacitor (C<sub>S</sub>)

The TPA2012D2 is a high-performance Class-D audio amplifier that requires adequate power supply decoupling to ensure the efficiency is high and total harmonic distortion (THD) is low. For higher frequency transients, spikes, or digital hash on the line, a good low equivalent-series-resistance (ESR) ceramic capacitor, typically 1 μF, placed as close as possible to the device PV<sub>DD</sub> lead works best. Placing this decoupling capacitor close to the TPA2012D2 is important for the efficiency of the Class-D amplifier, because any resistance or inductance in the trace between the device and the capacitor can cause a loss in efficiency. For filtering lower-frequency noise signals, a 4.7 μF or greater capacitor placed near the audio power amplifier would also help, but it is not required in most applications because of the high PSRR of this device.

**Table 1. Gain Setting**

G1	G0	GAIN (V/V)	GAIN (dB)	INPUT IMPEDANCE (R <sub>I</sub> ) (kΩ)
0	0	2	6	28.1
0	1	4	12	17.3
1	0	8	18	9.8
1	1	16	24	5.2

## Input Capacitors (C<sub>I</sub>)

The TPA2012D2 does not require input coupling capacitors if the design uses a differential source that is biased from 0.5 V to V<sub>DD</sub> - 0.8 V. If the input signal is not biased within the recommended common-mode input range, if high pass filtering is needed (see Figure 31), or if using a single-ended source (see Figure 32), input coupling capacitors are required.

The input capacitors and input resistors form a high-pass filter with the corner frequency, f<sub>c</sub>, determined in Equation 1.

$$f_c = \frac{1}{(2\pi R_I C_I)} \quad (1)$$

The value of the input capacitor is important to consider as it directly affects the bass (low frequency) performance of the circuit. Speakers in wireless phones cannot usually respond well to low frequencies, so the corner frequency can be set to block low frequencies in this application. Not using input capacitors can increase output offset.

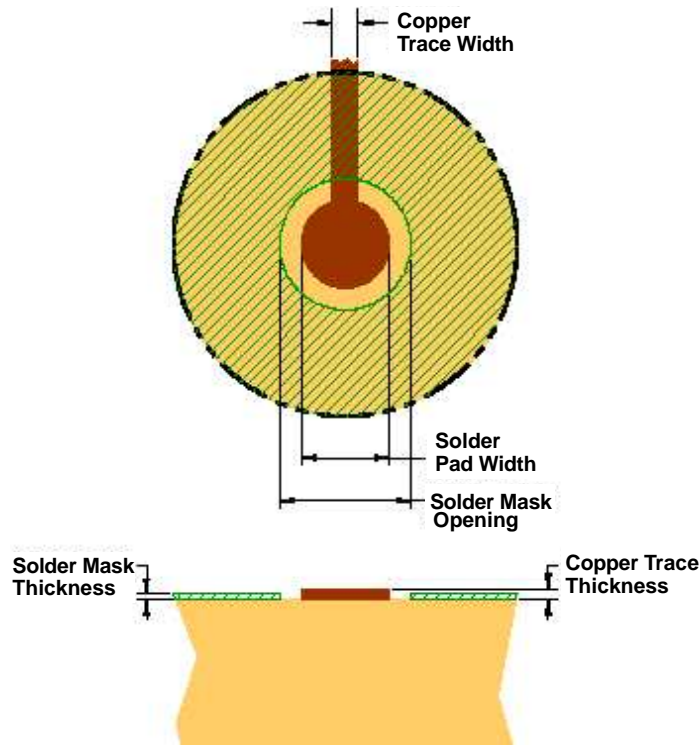
Equation 2 is used to solve for the input coupling capacitance.

$$C_I = \frac{1}{(2\pi R_I f_c)} \quad (2)$$

If the corner frequency is within the audio band, the capacitors should have a tolerance of ±10% or better, because any mismatch in capacitance causes an impedance mismatch at the corner frequency and below.

**BOARD LAYOUT**

In making the pad size for the WCSP balls, it is recommended that the layout use nonsolder mask defined (NSMD) land. With this method, the solder mask opening is made larger than the desired land area, and the opening size is defined by the copper pad width. Figure 33 and Table 2 shows the appropriate diameters for a WCSP layout. The TPA2012D2 evaluation module (EVM) layout is shown in the next section as a layout example.



**Figure 33. Land Pattern Dimensions**

**Table 2. Land Pattern Dimensions<sup>(1)(2)(3)(4)</sup>**

SOLDER PAD DEFINITIONS	COPPER PAD	SOLDER MASK <sup>(5)</sup> OPENING	COPPER THICKNESS	STENCIL <sup>(6)(7)</sup> OPENING	STENCIL THICKNESS
Nonsolder mask defined (NSMD)	275 μm (+0.0, -25 μm)	375 μm (+0.0, -25 μm)	1 oz max (32 μm)	275 μm x 275 μm Sq. (rounded corners)	125 μm thick

- (1) Circuit traces from NSMD defined PWB lands should be 75 μm to 100 μm wide in the exposed area inside the solder mask opening. Wider trace widths reduce device stand off and impact reliability.
- (2) Best reliability results are achieved when the PWB laminate glass transition temperature is above the operating the range of the intended application.
- (3) Recommend solder paste is Type 3 or Type 4.
- (4) For a PWB using a Ni/Au surface finish, the gold thickness should be less 0.5 μm to avoid a reduction in thermal fatigue performance.
- (5) Solder mask thickness should be less than 20 μm on top of the copper circuit pattern
- (6) Best solder stencil performance is achieved using laser cut stencils with electro polishing. Use of chemically etched stencils results in inferior solder paste volume control.
- (7) Trace routing away from WCSP device should be balanced in X & Y directions to avoid unintentional component movement due to solder wetting forces.

**Component Location**

Place all the external components very close to the TPA2012D2. Placing the decoupling capacitor, C<sub>S</sub>, close to the TPA2012D2 is important for the efficiency of the Class-D amplifier. Any resistance or inductance in the trace between the device and the capacitor can cause a loss in efficiency.

### Trace Width

Recommended trace width at the solder balls is 75  $\mu\text{m}$  to 100  $\mu\text{m}$  to prevent solder wicking onto wider PCB traces.

For high current pins ( $P_{V_{DD}}$ , PGND, and audio output pins) of the TPA2012D2, use 100- $\mu\text{m}$  trace widths at the solder balls and at least 500- $\mu\text{m}$  PCB traces to ensure proper performance and output power for the device.

For the remaining signals of the TPA2012D2, use 75- $\mu\text{m}$  to 100- $\mu\text{m}$  trace widths at the solder balls. The audio input pins (INR+/- and INL+/-) must run side-by-side to maximize common-mode noise cancellation.

### EFFICIENCY AND THERMAL INFORMATION

The maximum ambient temperature depends on the heat-sinking ability of the PCB system. The derating factor for the packages are shown in the dissipation rating table. Converting this to  $\theta_{JA}$  for the QFN package:

$$\theta_{JA} = \frac{1}{\text{Derating Factor}} = \frac{1}{0.041} = 24^{\circ}\text{C/W} \quad (3)$$

Given  $\theta_{JA}$  of 24 $^{\circ}\text{C/W}$ , the maximum allowable junction temperature of 150 $^{\circ}\text{C}$ , and the maximum internal dissipation of 1.5W (0.75 W per channel) for 2.1 W per channel, 4- $\Omega$  load, 5-V supply, from Figure 3, the maximum ambient temperature can be calculated with the following equation.

$$T_{A\text{Max}} = T_{J\text{Max}} - \theta_{JA} P_{D\text{max}} = 150 - 24 (1.5) = 114^{\circ}\text{C} \quad (4)$$

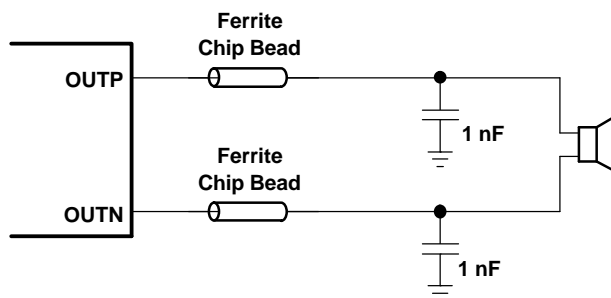
Equation 4 shows that the calculated maximum ambient temperature is 114 $^{\circ}\text{C}$  at maximum power dissipation with a 5-V supply and 4- $\Omega$  a load. The TPA2012D2 is designed with thermal protection that turns the device off when the junction temperature surpasses 150 $^{\circ}\text{C}$  to prevent damage to the IC. Also, using speakers more resistive than 4- $\Omega$  dramatically increases the thermal performance by reducing the output current and increasing the efficiency of the amplifier.

### FILTER FREE OPERATION AND FERRITE BEAD FILTERS

A ferrite bead filter can often be used if the design is failing radiated emissions without an LC filter and the frequency sensitive circuit is greater than 1 MHz. This filter functions well for circuits that just have to pass FCC and CE because FCC and CE only test radiated emissions greater than 30 MHz. When choosing a ferrite bead, choose one with high impedance at high frequencies, and very low impedance at low frequencies. In addition, select a ferrite bead with adequate current rating to prevent distortion of the output signal.

Use an LC output filter if there are low frequency (< 1 MHz) EMI sensitive circuits and/or there are long leads from amplifier to speaker.

Figure 34 shows typical ferrite bead and LC output filters.

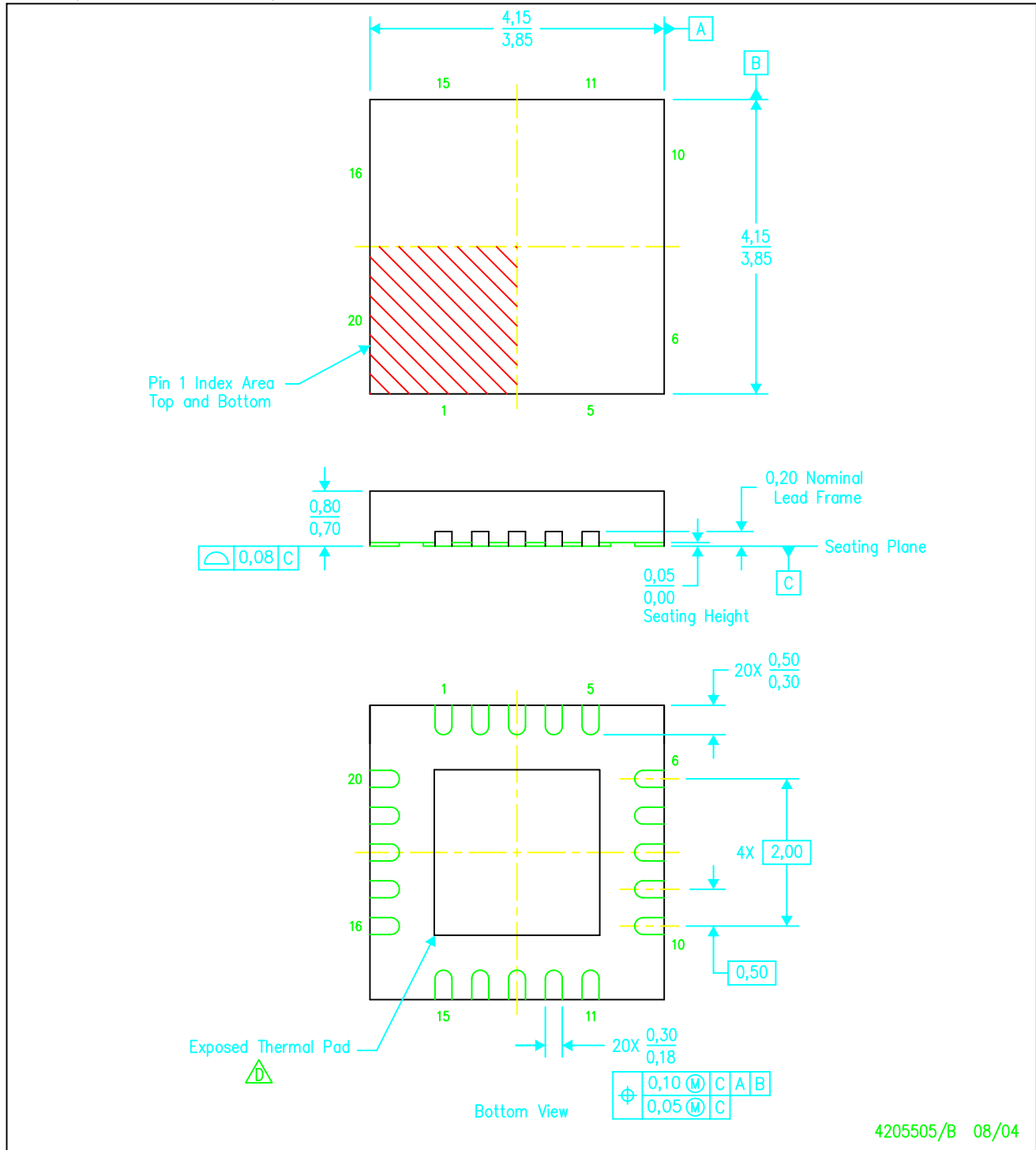



**Figure 34. Typical Ferrite Chip Bead Filter (Chip bead example: TDK: MPZ1608S221A)**

# MECHANICAL DATA

RTJ (S-PQFP-N20)

PLASTIC QUAD FLATPACK



- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5-1994.
  - B. This drawing is subject to change without notice.
  - C. QFN (Quad Flatpack No-Lead) package configuration.
  -  The package thermal pad must be soldered to the board for thermal and mechanical performance. See the Product Data Sheet for details regarding the exposed thermal pad dimensions.

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